LT1085LCC4

MILITARY VERSION

CERAMIC SURFACE MOUNT LOW DROPOUT POSITIVE ADJUSTABLE **VOLTAGE REGULATOR** FOR HI-REL APPLICATIONS

FEATURES

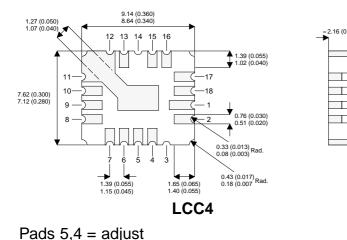
- Ceramic Surface Mount Hermetic Package
- Low Dropout Performance
- Output Current 3A
- Line Regulation 0.015% / V Typical.
- Load Regulation 0.1% Typical.
- Full Temperature Range (-55 to +150°C)

BLOCK DIAGRAM



V _{I-O}	Input–Output Differential Voltage		30V
P _D	Power Dissipation		Internally limited
V _{IN}	Operating Input Voltage		25V
TJ	Operating Junction Temperature Range	Control	–55 to 150°C
		Power	–55 to 200°C
Г _{STG}	Storage Temperature Range		–65 to 150°C
θ ^{JC}	Thermal Resistance (junction to case)		13°C/W

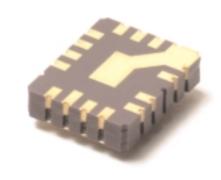
* Although the devices' maximum operating voltage is limited to 25V the devices are guaranteed to withstand transient input voltages up to 30V. For input voltages greater than the maximum operating input voltage, some degradation of specifications will occur.



Pads 6,7,8,9,10,11,13 = Vin Pads 1,2,15,16,17,18 = Vout



Dimensions in mm (inches)





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DESCRIPTION

The LT1085 is designed to provide 3A with higher efficiency than currently available devices. All internal circuitry is designed to operate down to 1V input to output differential and the dropout voltage is fully specified as a function of load current. Dropout is guaranteed at a maximum of 1.5V at maximum output current, decreasing at lower load currents. On-chip trimming adjusts the reference output voltage to 1%. Current limit is also trimmed, minimising the stress on both the regulator and power source circuitry under overload conditions.

ELECTRICAL CHARACTERISTICS (Pre Irradiation) $(T_J = 25^{\circ}C \text{ unless otherwise stated})$

	Parameter	Test Co	onditions	Min.	Тур.	Max.	Unit	
		$V_{IN} - V_{OUT} = 3V$	I _O = 10mA	1.238	1.250	1.252		
V _{REF}	Reference Voltage	$V_{IN} - V_{OUT} = 1.5$ to 7	15V I _O = 10mA to 3A	1.225	1.25	1.270	V	
			T _J = –55 to 125°C	1.225	1.25			
REG _{(LIN}	NE) Line Regulation	$I_{O} = 10 \text{mA} (V_{IN} - V_{O})$	_{DUT}) = 1.5 to 15V		0.015	0.2	%	
			T _J = –55 to 125°C		0.015	0.2		
		$I_0 = 10 \text{mA} (V_{\text{IN}} - V_0)$	_{OUT}) = 15 to 30V			0.5	/0	
			T _J = –55 to 125°C			0.5		
REG _{(LO}	AD) Load Regulation	$V_{IN} - V_{OUT} = 3V$			0.1	0.3	%	
	See notes 1,2	$I_{O} = 10$ mA to 3A	T _J = –55 to 125°C		0.2	0.4		
V _D	Dropout Voltage	$\Delta V_{REF} = 1\%$			1.3	1.5	V	
	See note 3	001	T _J = –55 to 125°C		1.5	1.5		
	Current Limit	$V_{IN} - V_{OUT} = 5V$	T _J = –55 to 125°C	3.2	4		А	
I _{CL}		$V_{IN} - V_{OUT} = 25V$	T _J = −55 to 125°C	0.2	0.2 0.5			
lQ	Quiescent Current	$V_{\rm IN} - V_{\rm OUT} = 5V$	T _J = −55 to 125°C		5	10	mA	
	Minimum Load Current ⁴				5	10		
REG _(THERM) Thermal Regulation		T _P = 30ms	T _A = 25°C		0.004	0.02	%/W	
R.	Ripple Rejection	f = 120Hz	$V_{IN} - V_{OUT} = 3V$	60	75		dB	
R _A		I _O = 3A	C _{ADJ} = 25μF					
I _{PIN}	Adjust Pin Current		T _J = –55 to 125°C		55	120	μΑ	
مامیر	Adjust Pin Current Change	V _{IN} – V _{OUT} = 1.5 to 15V			0.2	5	μA	
ΔI_{PIN}		$I_{O} = 10$ mA to 3A	T _J = −55 to 125°C		0.2	5		
т _S	Temperature Stability	T _J = –55 to 125°C			0.5		%	
	Long Term Stability	T _A = 125°C	T = 1000 Hrs		0.3		%	
V _N	RMS Output Noise	f = 10Hz to 10kHz	T _A = 25°C		0.003		%	

Notes:

1 Load and line regulation are measured at a constant junction temperature by low duty cycle pulse testing.

2 Power dissipation is determined by the input - output differential and the output current. Guaranteed maximum power dissipation will not be available over the full input - output voltage range.

3 Dropout voltage is specified over the full output current range of the device.